

View Online at <https://aerobasegroup.com/nsn/5961-00-764-2116>

Inclosure Material:

Metal all transistor

Overall Length:

0.200 inches all transistor and 0.260 inches all transistor

Terminal Length:

1.500 inches all transistor

Overall Diameter:

0.290 inches all transistor and 0.370 inches all transistor

Internal Configuration:

Junction contact all transistor

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-5 all transistor

Internal Junction Configuration:

Pnp all transistor

Component Function Relationship:

Matched

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal all transistor

Terminal Circle Diameter:

0.200 inches all transistor

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

-80.0 breakdown voltage, collector-to-base, emitter open all transistor and -80.0 breakdown voltage, collector-to-emitter, base open all transistor

Current Rating Per Characteristic:

-50.00 milliamperes source cutoff current all transistor

Power Rating Per Characteristic:

250.0 milliwatts small-signal input power, common-collector absolute all transistor

Terminal Type And Quantity:

3 uninsulated wire lead all transistor

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

No

Fiig:

A110a0